

## **BSR16**

## **PNP General Purpose Amplifier**

- This device designed for use as general purpose amplifier and switches requiring collector currents to 500mA.
- · Sourced from Process 63.
- See BCW68G for Characteristics.



1. Base 2. Emitter 3. Collector

## **PNP Epitaxial Silicon Transistor**

## Absolute Maximum Ratings\* Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	-60	V
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5.0	V
Ic	Collector Current - Continuous	-800	mA
T <sub>J</sub> , T <sub>ST</sub>	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted Symbol **Parameter Test Condition** Min. Тур. Max. Units **Off Characteristics** Collector-Emitter Breakdown Voltage $BV_{(BR)CEO}$ $I_C = -10 \text{mA}, I_B = 0$ ٧ -60 Collector-Base Breakdown Voltage $I_C = -100\mu A, I_E = 0$ ٧ BV<sub>(BR)CBO</sub> -60 Emitter-Base Breakdown Voltage ٧ $I_E=-10\mu A,\ I_C=0$ -5.0 $BV_{(BR)EBO}$ Collector Cut-off Current $V_{CB} = -50V$ -10 nΑ $I_{CBO}$ $V_{CB} = -50V, T_A = 150^{\circ}C$ -10 μΑ Collector Cut-off Current $V_{CE} = -30V, V_{EB} = -0.5V$ -50 nΑ $I_{CEX}$ $V_{CE} = -30V, V_{EB} = -3.0V$ Reverse Base Current -50 nΑ $I_{BEX}$ On Characteristics $h_{FF}$ DC Current Gain $I_C = -0.1 \text{mA}, V_{CE} = -10 \text{V}$ 75 $I_C = -1.0 \text{mA}, V_{CE} = -10 \text{V}$ 100 $I_C = -10 \text{mA}, V_{CE} = -10 \text{V}$ 100 $I_C = -150 \text{mA}, V_{CE} = -10 \text{V}$ 100 300 $I_C = -500 \text{mA}, V_{CE} = -10 \text{V}$ 50 $I_C = -150 \text{mA}, I_B = -15 \text{mA}$ -0.4 ٧ V<sub>CE</sub>(sat) Collector-Emitter Saturation Voltage $I_C = -500 \text{mA}, I_B = -50 \text{mA}$ -1.6 ٧ ٧ V<sub>BE</sub>(sat) Base-Emitter Saturation Voltage $I_C = -150 \text{mA}, I_B = -15 \text{mA}$ -1.3 ٧ $I_C = -500 \text{mA}, I_B = -50 \text{mA}$ -2.6 **Small Signal Characteristics** Current Gain Bandwidth Product $I_C = -50 \text{mA}, V_{CE} = -20 \text{V},$ $f = 100 \text{MHz}, T_A = 25 ^{\circ}\text{C}$ MHz 200 $C_{cb}$ **Output Capacitance** $V_{CB} = -10V, I_E = 0, f = 1.0MHz$ 8.0 pF $V_{CB} = -2.0V$ , $I_E = 0$ , f = 1.0MHz**Emitter-Base Capacitance** 30 $C_{eb}$ pF **Switching Characteristics** Turn-On Time $V_{CC} = -30V, I_{C} = -150mA,$ 45 $t_{on}$ ns $I_{B1} = -15 \text{mA}$ **Delay Time** 10 ns 40 Rise Time ns t<sub>r</sub> Turn-Off Time $V_{CC} = -30V, I_{C} = -150mA,$ 100 ns $t_{off}$ $I_{B1} = I_{B2} = -15 \text{mA}$

### Thermal Characteristics T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

<sup>\*</sup> Device mounted on FR-4 PCB 40mm × 40mm × 1.5mm

Storage Time

Fall Time

 $\mathsf{t}_{\mathsf{s}}$ 

 $t_f$ 

80

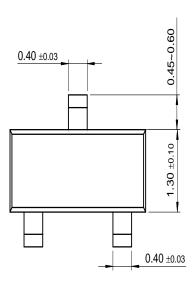
30

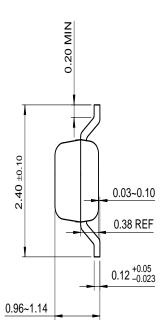
ns

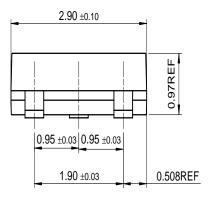
ns

# **Package Dimensions**

# **SOT-23**







Dimensions in Millimeters

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